

MOSFETs Silicon N-Channel MOS (DTMOSIV)

TK14G65W5

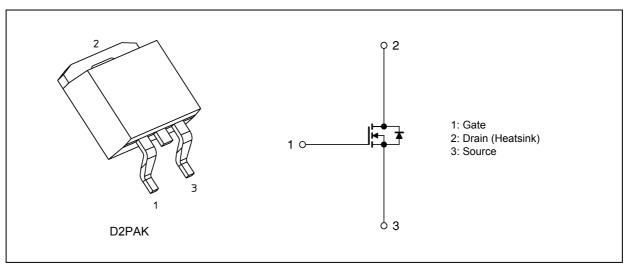
1. Applications

• Switching Voltage Regulators

2. Features

- (1) Fast reverse recovery time: $t_{rr} = 100 \text{ ns (typ.)}$
- (2) Low drain-source on-resistance: $R_{DS(ON)}$ = 0.25 Ω (typ.) by using Super Junction Structure: DTMOS
- (3) Easy to control Gate switching
- (4) Enhancement mode: $V_{th} = 3$ to 4.5 V ($V_{DS} = 10$ V, $I_D = 0.69$ mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (Ta = 25°C unless otherwise specified)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	650	V
Gate-source voltage		V _{GSS}	±30	
Drain current (DC)	(Note 1)	I _D	13.7	Α
Drain current (pulsed)	(Note 1)	I _{DP}	54.8	1
Power dissipation (T _c = 1	25°C)	P _D	130	W
Single-pulse avalanche energy	(Note 2)	E _{AS}	194	mJ
Avalanche current		I _{AR}	3.7	Α
Reverse drain current (DC)	(Note 1)	I _{DR}	13.7	
Reverse drain current (pulsed)	(Note 1)	I _{DRP}	54.8	1
Channel temperature		T _{ch}	150	°C
Storage temperature		T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	0.962	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 25 mH, R_G = 25 Ω , I_{AR} = 3.7 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



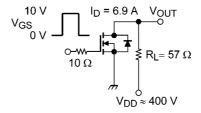
6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_		±1	μА
Drain cut-off current	I _{DSS}	V _{DS} = 650 V, V _{GS} = 0 V	_	_	100	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	650	_	_	V
Gate threshold voltage	V_{th}	V _{DS} = 10 V, I _D = 0.69 mA	3	_	4.5	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 6.9 A	_	0.25	0.3	Ω

6.2. Dynamic Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 300 V, V _{GS} = 0 V, f = 1 MHz	_	1300	_	pF
Reverse transfer capacitance	C _{rss}		_	4	_	
Output capacitance	C _{oss}		_	35	_	
Effective output capacitance	C _{o(er)}	V _{DS} = 0 to 400 V, V _{GS} = 0 V	_	55	_	
Gate resistance	r _g	V _{DS} = OPEN, f = 1 MHz	_	6	_	Ω
Switching time (rise time)	t _r	See Figure 6.2.1	_	40	_	ns
Switching time (turn-on time)	t _{on}		_	90	_	
Switching time (fall time)	t _f		_	7	_	
Switching time (turn-off time)	t _{off}		_	110	_	
MOSFET dv/dt ruggedness	dv/dt	V _{DD} = 0 to 400 V, I _D = 6.9 A	50	_		V/ns



Duty \leq 1 %, $t_W=$ 10 μs

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 13.7 \text{ A}$	1	40	1	nC
Gate-source charge 1	Q _{gs1}			13		
Gate-drain charge	Q_{gd}		_	22	_	

6.4. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V_{DSF}	I _{DR} = 13.7 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 6.9 A, V _{GS} = 0 V	_	100	160	ns
Reverse recovery charge	Q _{rr}	-dI _{DR} /dt = 100 A/μs		0.6	_	μС
Peak reverse recovery current	I _{rr}		_	12	_	Α
Diode dv/dt ruggedness	dv/dt	I _{DR} = 6.9 A, V _{GS} = 0 V, V _{DD} = 400 V	50	_	_	V/ns



7. Marking

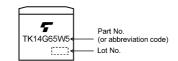
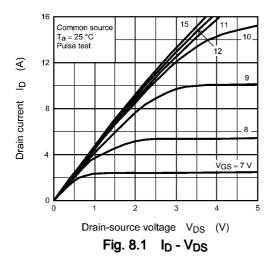
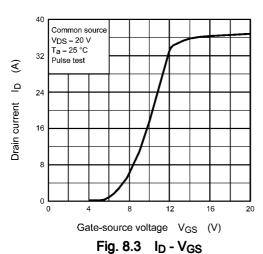


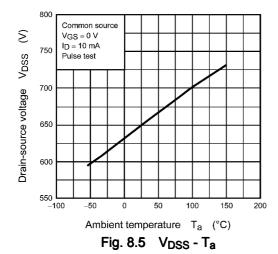
Fig. 7.1 Marking

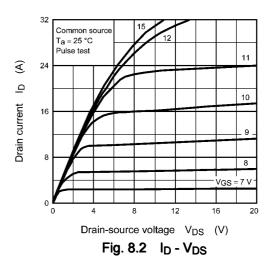
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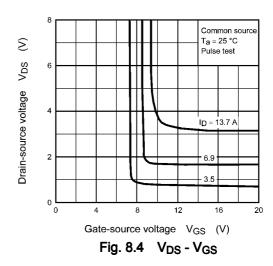
8. Characteristics Curves (Note)











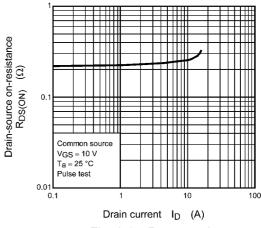


Fig. 8.6 R_{DS(ON)} - I_D

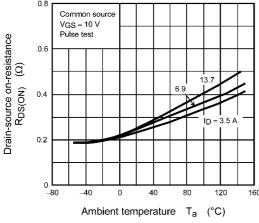


Fig. 8.7 R_{DS(ON)} - T_a

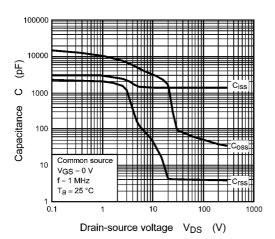


Fig. 8.9 C - V_{DS}

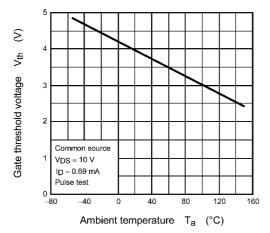


Fig. 8.11 V_{th} - T_a

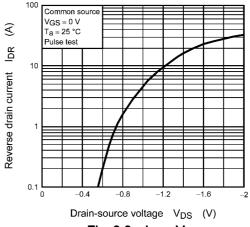


Fig. 8.8 I_{DR} - V_{DS}

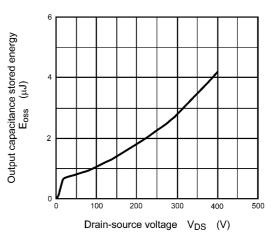


Fig. 8.10 Eoss - V_{DS}

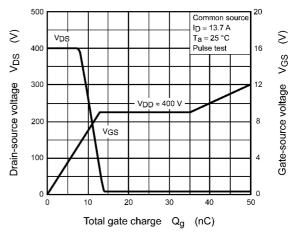


Fig. 8.12 Dynamic Input/Output Characteristics

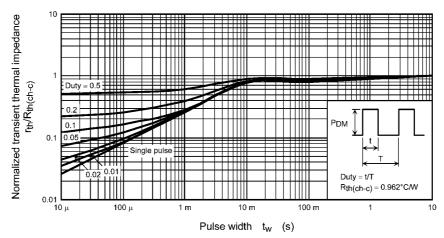
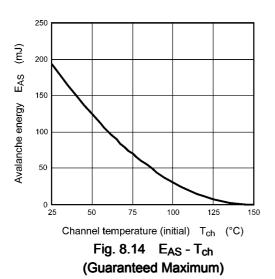
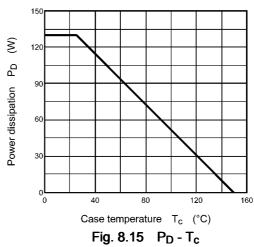


Fig. 8.13 rth - tw (Guaranteed Maximum)





(Guaranteed Maximum)

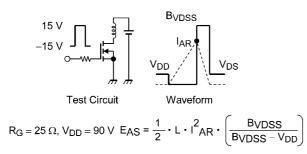


Fig. 8.16 Test Circuit/Waveform

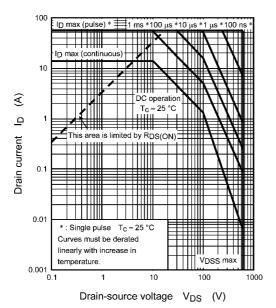


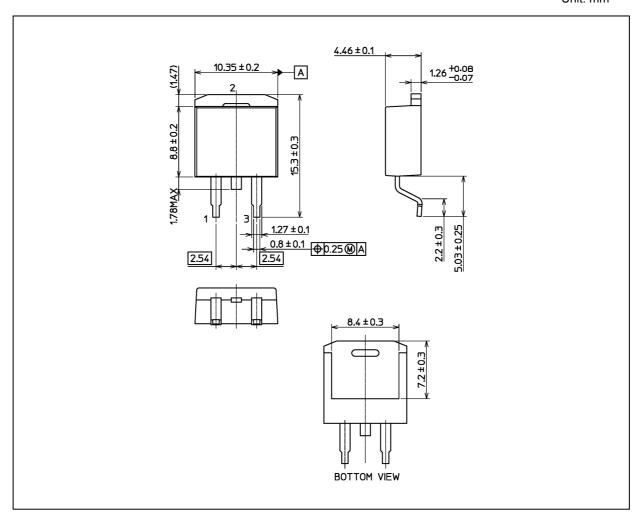
Fig. 8.17 Safe Operating Area (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 1.59 g (typ.)

	Package Name(s)
TOSHIBA: 2-11H1A	
Nickname: D2PAK	



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